Volts

HER101 THRU HER108





High Efficiency Rectifier

Current: Package: DO-41 Ampers

Features

Voltage:

- NH'S High Efficiency Rectifier Chip Technology
- Low Switching Loss For High Efficiency

50~1000

- Low Leakage Current For High Reliability
- Ultra Fast Switching Speed

Mechanical Data

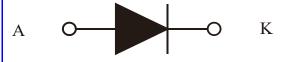
- Case: Molded With UL-94 ClassV-0 Recognized, RoHS-Compliant
- Polarity: Look At The Diagram And Polarity On The Right
- Terminals: Tin Plated Leads, Solderable Per J-STD-002 And JESD22-B102

Typical Applications

- Switch Mode Power Supplies (SMPS)
- Fast Chargers
- LED Driver And Monitor Lighting
- Automotive Electronics And Charging Posts



Polarity:



Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

Maximum Ratings (Ta=25℃ Unless Otherwise Specified)										
Parameter	Test Conditions	Symbol	HER 101	HER 102	HER 103	HER 105	HER 106	HER 107	HER 108	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltag		V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		$I_{F(AV)}$				1				A
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I_{FSM}	30				A			
Current Squared Time	t< 8.3ms	I ² t	3.7					A ² sec		

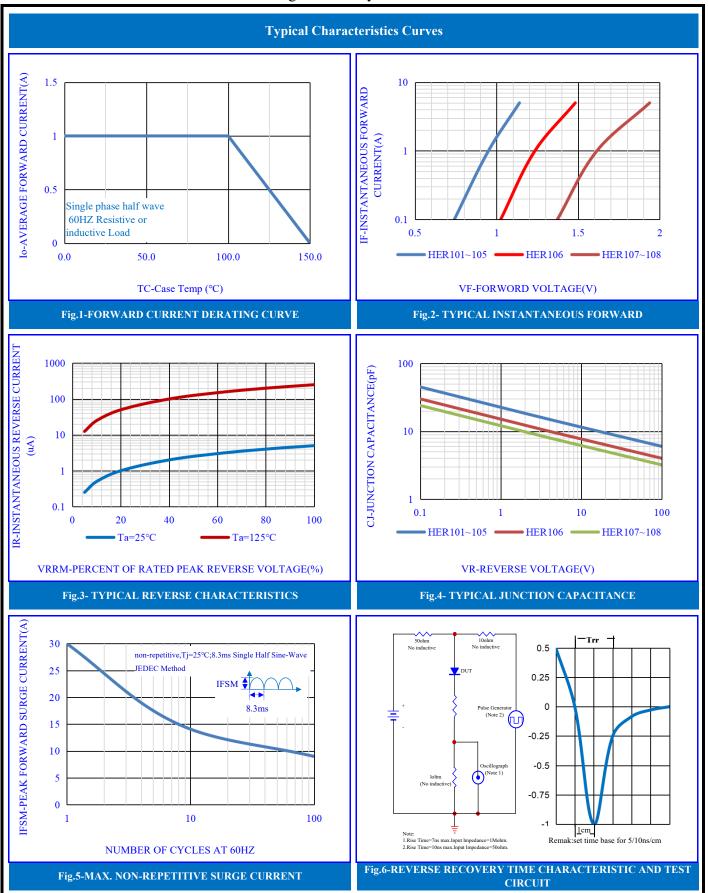
Electrical Characteristcs (Ta=25°C Unless Otherwise Specified)										
Parameter	Test Conditions	Symbol	HER 101	HER 102	HER 103	HER 105	HER 106	HER 107	HER 108	Unit
Maximum Instaneous Forward Voltage	I_F = 1.0 A	$\mathbf{V_F}$	V _F 1.00 1.30		1.30	1.70		V		
Maximum DC Reverse Current at Rated DC Blocking Voltage	Ta=25°C , V_R =VRRM Ta=125°C , V_R =VRRM*80%	I _{RRM} 5 200			uA uA					
Typical Junction Capacitance	4 V,1MHz	$C_{\mathbf{J}}$	$C_{\rm J}$ 15 10 8		8	pF				
Maximum Reverse Recovery Time	IF=0.5A, IR=1.0A, IRR=0.25A	Trr	50 75					nS		

Thermal Characteristcs (Ta=25°	C Unless Otherwise Specified)								
Parameter	Test Conditions	Symbol	HER 101	HER 102	HER 103	HER 105	HER 106	HER 107	HER 108	Unit
Operating Junction Temperature Range	Operating Junction Temperature Range T _J					-55~150)			က
Storage Temperature Range		T _{STD}	-55~150							
Thermal Resistance Junction To Ambient										
With Steady-State With Ta=25 ℃		$R_{\theta JA}$				78.0				°C/W
Thermal Resistance Junction-Case	At 0.375"(9.5mm) lead length	R aic 25.0] C/W					
With Steady-State	Mounted On vertical P.C. Board	$\mathbf{K}_{ ext{ heta}J ext{ ext{ ext{ ext{ ext{ ext{ ext{ ext{$	$\mathbf{R}_{\mathbf{\theta JC}}$ 25.0							
Notes: 1 Pulse Test: 200 Us Pulse Width 19/ Puts Cycle										

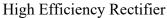
Http://www.nh-semicon.com Date:2014-10-20 Rev.:A/1 Page: 1 of

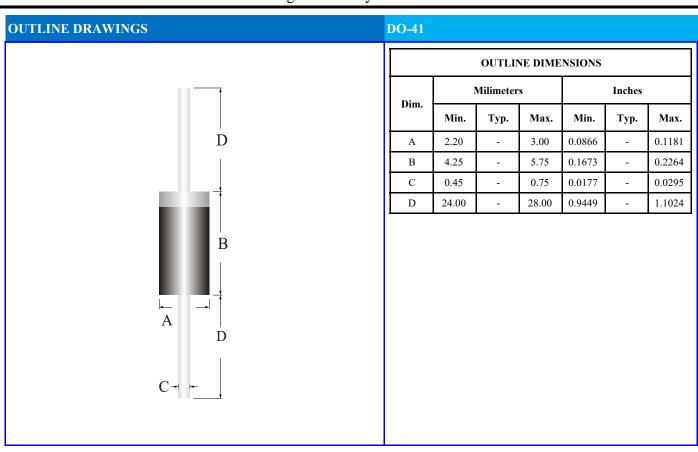


High Efficiency Rectifier

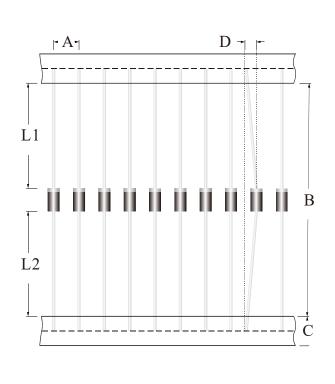








COMPONENT PITCH DIMENSION DIAGRAM



DO-41

OUTLINE DIMENSIONS									
ъ.	1	Milimeter	s	Inches					
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.			
A	4.50	-	5.50	0.1772	ı	0.2165			
В	51.00	-	53.00	2.0079	-	2.0866			
С	5.50	-	6.50	0.2165	-	0.2559			
D	-	-	1.20	-	ı	0.0472			
L2-L1	-	-	1.00	-	-	0.0394			





High Efficiency Rectifier

MARKING	MARKING INSTRUCTION
	NH=Niuhang Trademark HER1xx=Model,xx=01,02,03,05,06,07,08 FF=Inernal Code,According To Actual Changes White band denotes cathode
HER1xx	

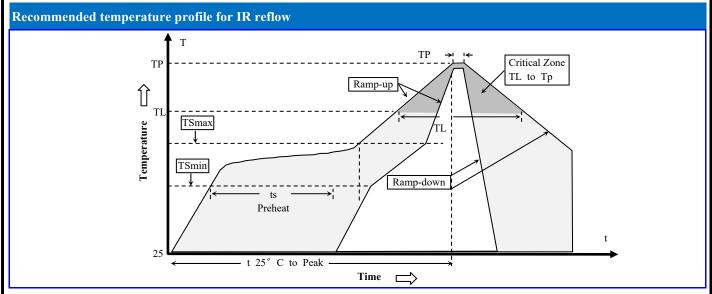
PACKING INFOR	RMATIO	N				
Package Type	Package Code	Productor Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)
DO-41	P1	0.208	Tape	5000	5000	50000

Http://www.nh-semicon.com Date:2014-10-20 Rev.:A/1 Page: 4 of 6



High Efficiency Rectifier

Recommended wave soldering condition								
Product	Peak Temperature	Soldering Time						
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds						



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(TS min) -Temperature Max(TS max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package, measured on the package body surface.

Http://www.nh-semicon.com Date:2014-10-20 Rev.:A/1 Page: 5 of 6

Specification For Approval

HER101 THRU HER108



High Efficiency Rectifier

Disclaimer

- Reproducing and modifying informatiom of the document is prohibited without permission from Niuhang Electronics Technology Co., LTD
- Niuhang Electronics Technology Co., LTD. reserves the rights to make changes of the content herein the document anytime without notification.
- Niuhang Electronics Technology Co., LTD. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Niuhang Electronics Technology Co., LTD. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Niuhang Electronics Technology Co., LTD.makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments. transportation equipment, aerospae machinery et cetera. Customers usin or selling these products for use in such applications do so at their own rish and agree to fully indemnify Niuhang Electronics Technology Co., LTD. for any damages resulting resulting from such improper use or sale.
- When the appearance of the product and chip size does not change, in order to product the customer. quality, change the internal structure and the production process Niuhang can not notify

Http://www.nh-semicon.com Date:2014-10-20 Rev.:A/1 Page: 6 of 6